TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

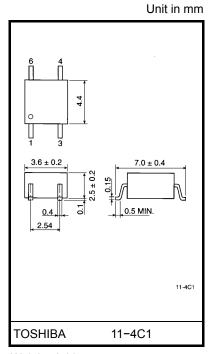
TLP126

Programmable Controllers AC / DC-Input Module Telecommunication

The TOSHIBA mini flat coupler TLP126 is a small outline coupler, suitable for surface mount assembly.

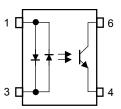
TLP126 consists of a photo transistor, optically coupled to a gallium arsenide infrared emitting diode connected inverse parallel, and provides high CTR at low AC input current.

- Collector-emitter voltage: 80 V (min.)
- Current transfer ratio: 100% (min.)
- Isolation voltage: 3750Vrms (min.)
- UL recognized: UL1577, file No. E67349



Weight: 0.09 g

Pin Configurations (top view)



- 1: Anode, Cathode
- 3 : Cathode, Anode
- 4 : Emitter
- 6: Collector

Absolute Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit
	Forward current	I _{F(RMS)}	50	mA
Ω	Forward current derating (Ta≥ 53°C) Δ	ΔI _F / °C	-0.7	mA / °C
LED	Peak forward current(100µs pulse,100pps)	IFP	1	Α
	Junction temperature	Tj	125	°C
	Collector-emitter voltage	V _{CEO}	80	V
	Emitter-collector voltage	V _{ECO}	7	V
ō	Collector current	IC	50	mA
Detector	Peak collector current(10ms pulse,100pps)	I _{CP}	100	mA
ă	Power dissipation	PC	150	mW
	Power dissipation derating (Ta ≥ 25°C)	ΔP _C / °C	-1.5	mW / °C
	Junction temperature	Tj	125	°C
Stor	rage temperature range	T _{stg}	-55~125	°C
Оре	erating temperature range	T _{opr}	-55~100	°C
Lea	d soldering temperature(10 sec.)	T _{sold}	260	°C
Tota	al package power dissipation	PT	200	mW
Tota	al package power dissipation derating (Ta≥25°C)	ΔP _T / °C	-2.0	mW / °C
Isola	ation voltage (AC, 1min., RH ≤ 60%) (Note 1)	BVS	3750	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note 1) Device considered a two terminal device: Pins1, and 3 shorted together and 4 and 6 shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	V _{CC}	_	5	48	V
Forward current	I _{F(RMS)}	_	1.6	20	mA
Collector current	IC	_	1	10	mA
Operating temperature	T _{opr}	-25	_	75	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Individual Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
LED	Forward voltage	V_{F}	I _F = ±10 mA	1.0	1.15	1.3	V
ILE	Capacitance	C _T	V = 0, f = 1 MHz		60	_	pF
	Collector–emitter breakdown voltage	V _(BR) CEO	I _C = 0.5 mA	80	_		٧
Detector	Emitter-collector breakdown voltage	V _(BR) ECO	I _E = 0.1 mA	7	_		٧
	Collector dark current	la-a	V _{CE} = 48 V	_	10	100	nA
	Collector dark current	ICEO	V _{CE} = 48 V, Ta = 85°C		2	50	μΑ
	Capacitance collector to emitter	C _{CE}	V = 0, f = 1 MHz		12	_	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	MIn.	Тур.	Max.	Unit
Current transfer ratio	I _C / I _F	$I_F = \pm 1$ mA, $V_{CE} = 0.5$ V	100	_	1200	%
Low input CTR	Ic / I _{F (low)}	IF = ±0.5 mA, V _{CE} = 1.5 V	50	_	_	%
Collector-emitter	Vo= ()	I _C = 0.5 mA, I _F = ±1 mA	_	_	0.4	V
saturation voltage	V _{CE} (sat)	I _C = 1 mA, I _F = ±1 mA	_	0.2	-	
Off-state collector current	I _{C(off)}	V _F = ± 0.7V, V _{CE} = 48 V	_	1	10	μΑ
CTR symmetry	I _{C (ratio)}	$I_{C} (I_{F} = -1mA) / I_{C} (I_{F} = 1mA)$	0.3	_	3	_

Coupled Electrical Characteristics (Ta = $-25\sim75^{\circ}$ C)

Characteristic	Symbol	Test Condition	Mln.	Тур.	Max.	Unit
Current transfer ratio	I _C / I _F	I _F = 1 mA, V _{CE} = 0.5 V	50	_	_	%
Low input CTR	I _C / I _{F (low)}	IF = 0.5 mA, V _{CE} = 1.5 V	_	50	_	%

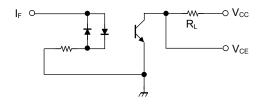
Isolation characteristics (Ta = 25°C)

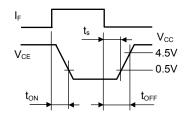
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Capacitance input to output	Cs	V _S = 0, f = 1 MHz	_	0.8	_	pF
Isolation resistance	R _S	V _S = 500 V	5×10 ¹⁰	10 ¹⁴	_	Ω
		AC, 1 minute	3750	_	_	Vrms
Isolation voltage	BV_S	AC, 1 second, in oil	_ 100	10000	_	VIIIIS
		DC, 1 minute, in oil	_	10000	_	Vdc

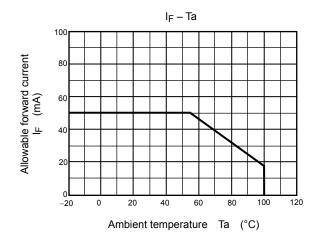
Switching Characteristics (Ta = 25°C)

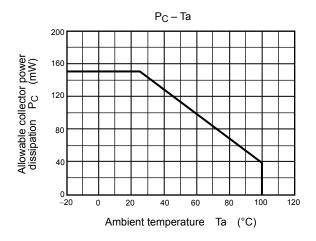
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Rise time	t _r	V _{CC} = 10 V, I _C = 2 mA	_	8	_	
Fall time	t _f		_	8	_	μs
Turn-on time	t _{on}	$R_L = 100\Omega$	_	10	_	μδ
Turn-off time	t _{off}		_	8	_	
Turn-on time	t _{ON}		_	10	_	
Storage time	ts	$R_L = 4.7 \text{ k}\Omega$ (Fig.1) $V_{CC} = 5 \text{ V}, I_F = \pm 1.6 \text{ mA}$	_	50	_	μs
Turn-off time	tOFF		_	300	_	

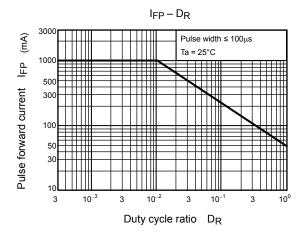
Fig. 1 Switching time test circuit

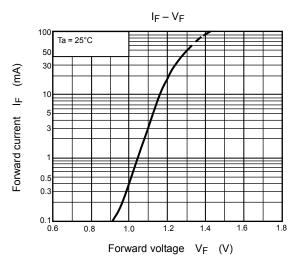


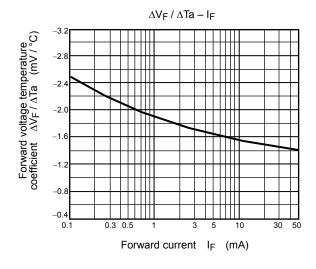


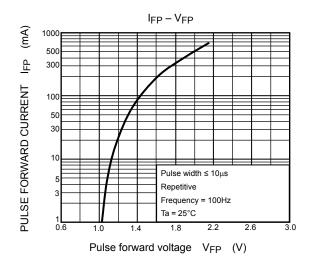


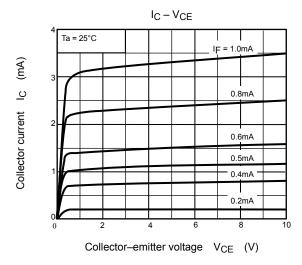


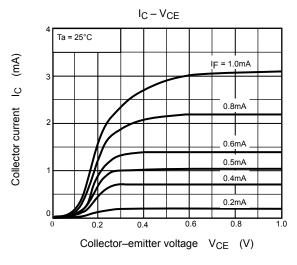


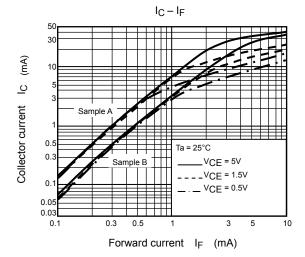


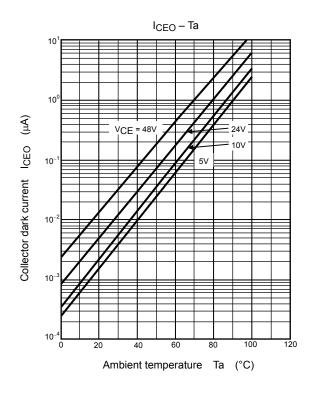


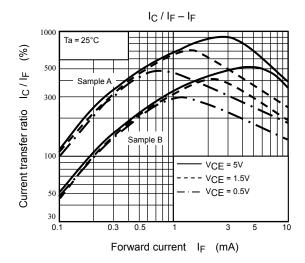




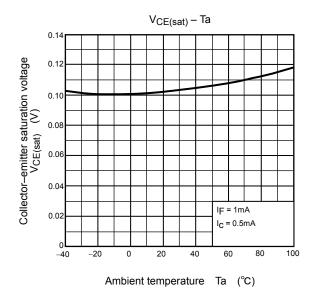


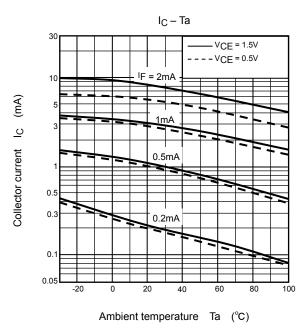


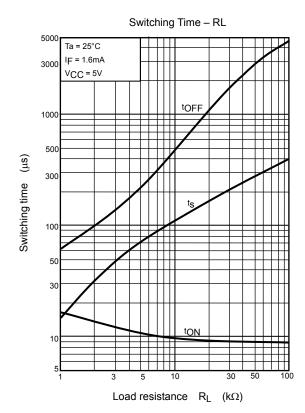




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